



SOT-23



Pin Definition:

1. Gate
2. Source
3. Drain

Note:

MSL 1 (Moisture Sensitivity Level)
per J-STD-020

TSM650P02CX

20V P-Channel Power MOSFET

Key Parameter Performance

Parameter	Value	Unit
V_{DS}	-20	V
$R_{DS(on)}$ (max)	$V_{GS} = -4.5V$	65
	$V_{GS} = -2.5V$	85
	$V_{GS} = -1.8V$	130
Q_g	6.4	nC

Features

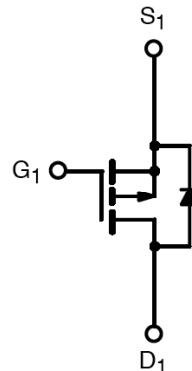
- Fast switching
- Suited for -1.8V gate drive applications
- Halogen-free

Ordering Information

Ordering code	Package	Packing
TSM650P02CX RFG	SOT-23	3kcs / 7" Reel

Note: Halogen-free according to IEC 61249-2-21 definition

Block Diagram



P-Channel MOSFET

Absolute Maximum Ratings ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-20	V
Gate-Source Voltage	V_{GS}	± 10	V
Continuous Drain Current	I_D	-4.1	A
		-2.6	A
Pulsed Drain Current ^(Note 1)	I_{DM}	-16.4	A
Power Dissipation @ $T_C = 25^\circ\text{C}$	P_D	1.56	W
Operating Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150	$^\circ\text{C}$

Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Ambient	$R_{\Theta JA}$	80	$^\circ\text{C/W}$


Electrical Specifications ($T_C = 25^\circ\text{C}$ unless otherwise noted)

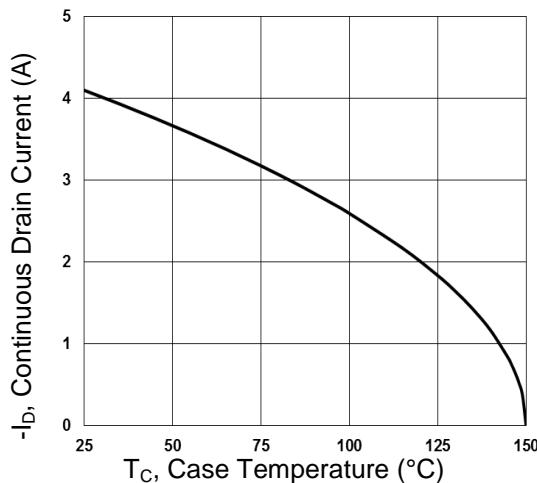
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{V}, I_D = -250\mu\text{A}$	BV_{DSS}	-20	--	--	V
Drain-Source On-State Resistance	$V_{GS} = -4.5\text{V}, I_D = -3\text{A}$	$R_{DS(on)}$	--	52	65	$\text{m}\Omega$
	$V_{GS} = -2.5\text{V}, I_D = -2\text{A}$		--	73	85	
	$V_{GS} = -1.8\text{V}, I_D = -1.5\text{A}$		--	105	130	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$	$V_{GS(\text{TH})}$	-0.4	-0.6	-0.8	V
Zero Gate Voltage Drain Current	$V_{DS} = -20\text{V}, V_{GS} = 0\text{V}$	I_{DSS}	--	--	-1	μA
	$V_{DS} = -16\text{V}, T_J = 125^\circ\text{C}$		--	--	-10	
Gate Body Leakage	$V_{GS} = \pm 10\text{V}, V_{DS} = 0\text{V}$	I_{GSS}	--	--	± 100	nA
Forward Transconductance ^(Note 2)	$V_{DS} = -10\text{V}, I_D = -3\text{A}$	g_{fs}	--	5.5	--	S
Dynamic						
Total Gate Charge ^(Note 2,3)	$V_{DS} = -10\text{V}, I_D = -3\text{A}, V_{GS} = -4.5\text{V}$	Q_g	--	6.4	--	nC
Gate-Source Charge ^(Note 2,3)		Q_{gs}	--	0.9	--	
Gate-Drain Charge ^(Note 2,3)		Q_{gd}	--	1.6	--	
Input Capacitance	$V_{DS} = -10\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$	C_{iss}	--	515	--	pF
Output Capacitance		C_{oss}	--	55	--	
Reverse Transfer Capacitance		C_{rss}	--	20	--	
Switching						
Turn-On Delay Time ^(Note 2,3)	$V_{DD} = -10\text{V}, I_D = -1\text{A}, V_{GS} = -4.5\text{V}, R_{GEN} = 25\Omega$	$t_{d(on)}$	--	5	--	ns
Turn-On Rise Time ^(Note 2,3)		t_r	--	17.4	--	
Turn-Off Delay Time ^(Note 2,3)		$t_{d(off)}$	--	40.7	--	
Turn-Off Fall Time ^(Note 2,3)		t_f	--	11.4	--	
Source-Drain Diode Ratings and Characteristic						
Maximum Continuous Drain-Source Diode Forward Current	Integral reverse diode in the MOSFET	I_S	--	--	-4.1	A
Maximum Pulse Drain-Source Diode Forward Current		I_{SM}	--	--	-16.4	A
Diode-Source Forward Voltage	$V_{GS} = 0\text{V}, I_S = -1\text{A}$	V_{SD}	--	--	-1	V

Note:

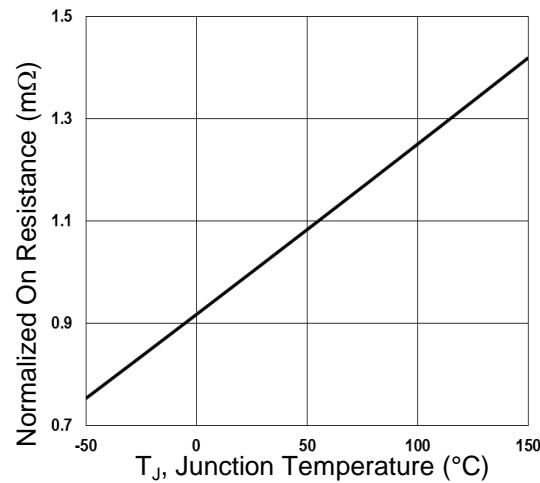
1. Pulse width limited by safe operating area
2. Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
3. Switching time is essentially independent of operating temperature.

Electrical Characteristics Curve

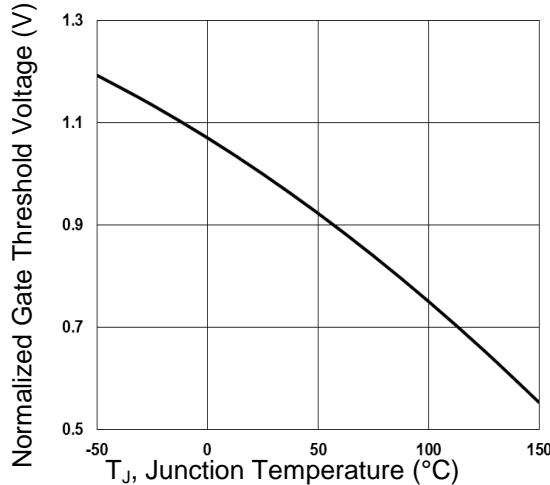
Continuous Drain Current vs. T_C



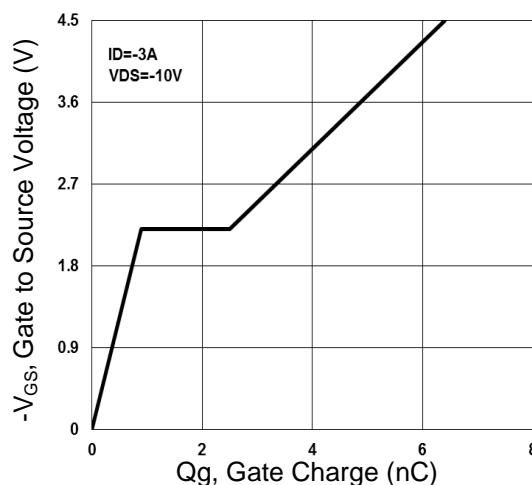
Normalized $R_{DS(on)}$ VS. T_J



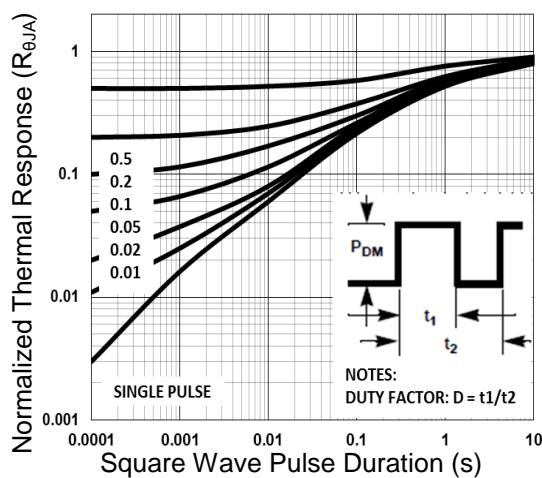
Threshold Voltage vs. Junction Temperature



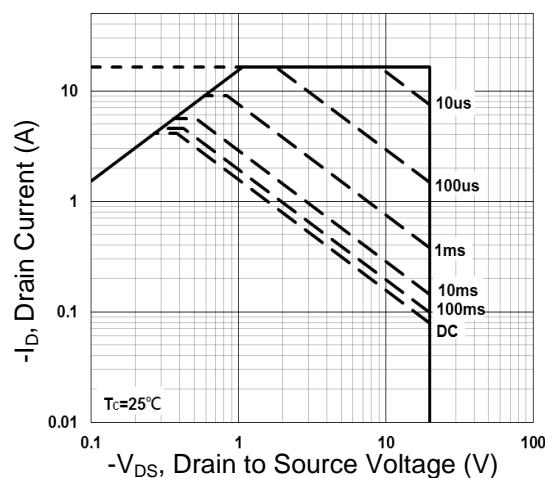
Gate Charge Waveform



Normalized Thermal Transient Impedance Curve

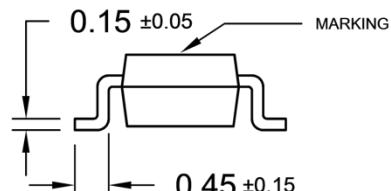
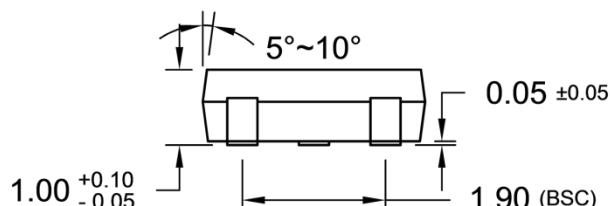
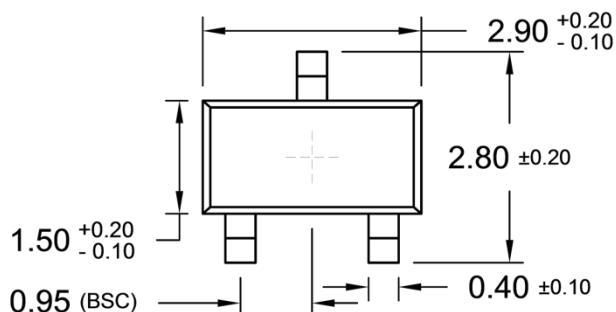


Maximum Safe Operating Area



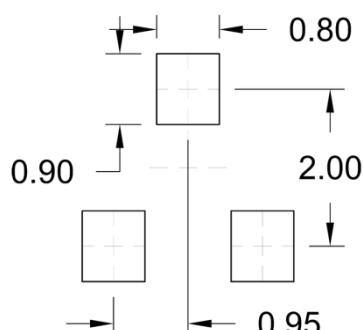


SOT-23 Mechanical Drawing

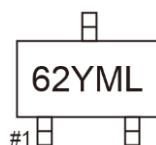


Unit: Millimeters

SUGGESTED PAD LAYOUT (Unit: Millimeters)



Marking Diagram



- 62** = Device Code
- Y** = Year Code
- M** = Month Code for Halogen Free Product
(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apr, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep,
X=Oct, **Y**=Nov, **Z**=Dec)
- L** = Lot Code

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